

SuperMOS - SOT-23 -30V BV_{DSS} , 60m Ω $R_{DS(on)}$, P-channel MOSFET

1. Description

The AO3409-ES is P-Channel enhancement MOS Field Effect Transistor. Uses advanced technology and design to provide excellent $R_{DS(on)}$ with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product AO3409-ES is Pb-free.

2. Features

- -30V, $R_{DS(on)}$ =60m Ω (Typ.) @ V_{GS} =-10V
 $R_{DS(on)}$ =105m Ω (Typ.) @ V_{GS} =-4.5V
- Fast Switching
- High density cell design for low $R_{DS(on)}$
- Material: Halogen free
- Reliable and rugged
- Avalanche Rated
- Low leakage current

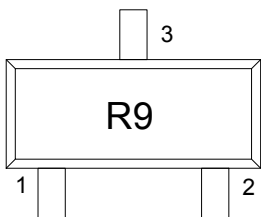
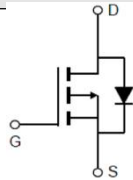
3. Applications

- PWM applications
- Load switch
- Power management in portable/desktop PCs
- DC/DC conversion

4. Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel size
AO3409-ES	SOT-23	R9	Halogen free	Tape & Reel	3,000 PCS	UL 94V-0	7 inches

5. Pin Configuration and Functions

Pin	Function	Outline	Circuit Diagram
1	Gate		
2	Source		
3	Drain		

6. Specification

Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		BV_{DSS}	-30	V
Gate-Source Voltage		V_{GS}	±20	V
Continuous Drain Current	$T_A=25^{\circ}\text{C}$	I_D	-3.8	A
	$T_A=100^{\circ}\text{C}$		-2.3	
Maximum Power Dissipation		P_D	1.14	W
Pulsed Drain Current		I_{DM}	-15.2	A
Operating Junction Temperature		T_J	150	°C
Storage Temperature Range		T_{stg}	-55 to +150	°C

Thermal resistance ratings

Single Operation				
Parameter		Symbol	Max	Unit
Junction-to-Ambient Thermal Resistance		$R_{\theta JA}$	110	°C/W

AO3409-ES

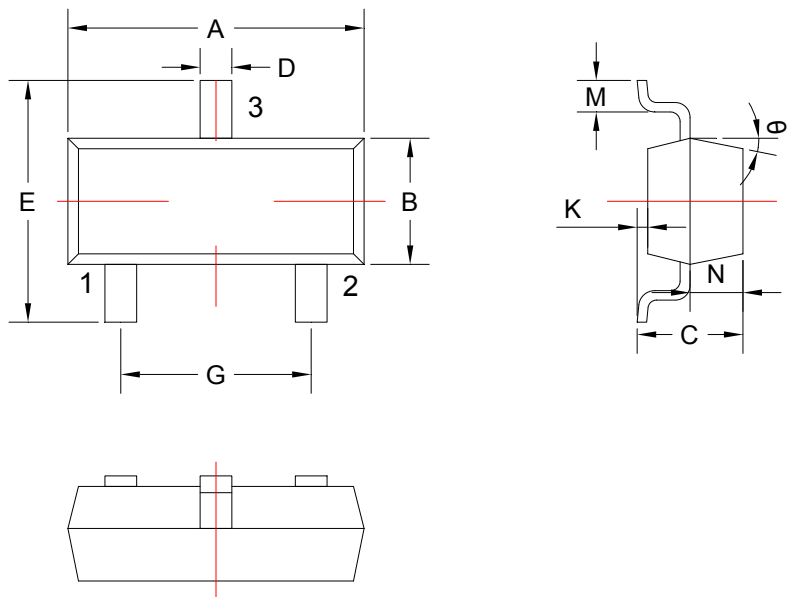
Rev-1.2

Electrical Characteristics

At TA = 25°C unless otherwise specified

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-30			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} =0V, V _{DS} =-30V			-1	uA
Gate-to-source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V			±100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{GS} =V _{DS} , I _D =-250uA	-1.2		-2.5	V
Drain-to-source On-resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-3.0A		60	75	mΩ
		V _{GS} =-4.5V, I _D =-2.0A		105	132	
CHARGES AND CAPACITANCES						
Input Capacitance	C _{ISS}	V _{GS} =0V, V _{DS} =-15V f=1MHz		260		pF
Output Capacitance	C _{OSS}			52		
Reverse Transfer Capacitance	C _{RSS}			41		
Total Gate Charge	Q _{G(TOT)}	V _{GS} =-10V, V _{DS} =-15V I _D =-3A		5.5		nC
Gate-to-Source Charge	Q _{GS}			0.9		
Gate-to-Drain Charge	Q _{GD}			1.3		
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	t _{d(ON)}	V _{GS} =-10V, V _{DD} =-15V I _D =-3A, R _G =2.5Ω		10		ns
Rise Time	t _r			54		
Turn-Off Delay Time	t _{d(OFF)}			16		
Fall Time	t _f			8		
BODY DIODE CHARACTERISTICS						
Forward Voltage	V _{SD}	V _{GS} =0V, I _{SD} =-3.0A			-1.5	V

7. Dimension (SOT-23)



COMMON DIMENSIONS CUNITS MEASURE=MILLIMETER					
SYMBOL	MIN	MAX	SYMBOL	MIN	MAX
A	2.85	3.04	G	1.80	2.00
B	1.20	1.40	K	0	0.10
C	0.90	1.10	M	0.20	-
D	0.40	0.50	N	0.50	0.70
E	2.25	2.55	θ	5°	9°

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